

DESCRIPTION

The SPN1443 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

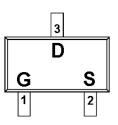
APPLICATIONS

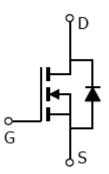
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

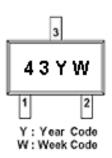
- 30V/2.8A,RDS(ON)= $65m\Omega$ @VGS=10V
- 30V/2.3A,RDS(ON)= $90m\Omega$ @VGS=4.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-323 (SC-70) package design

PIN CONFIGURATION (SOT-323; SC-70)





PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1443S32RGB	SOT-323	43

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN1443S32RGB: Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

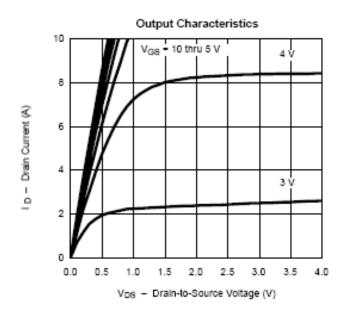
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Drain Current(TJ=150°C)	Ta=25°C	In	2.8	A	
Continuous Drain Current(13–130 C)	Ta=70°C	Id	2.3	A	
Pulsed Drain Current		Ірм	10	A	
Continuous Source Current(Diode Conduction)		Is	1.25	A	
Down Dissination	Ta=25°C	Drs	0.33	***	
Power Dissipation	Ta=70°C	Pd	0.21	W	
Operating Junction Temperature		τŢ	150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	100	°C/W	

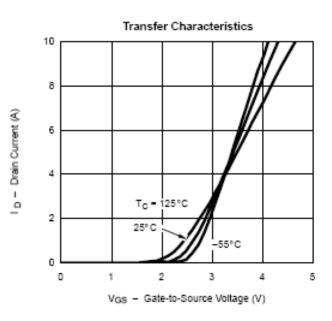
ELECTRICAL CHARACTERISTICS

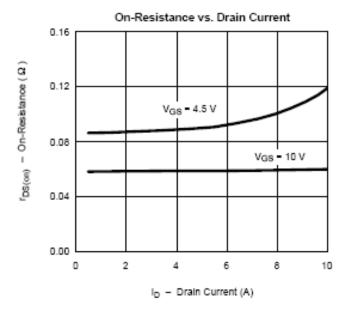
(TA=25°C Unless otherwise noted)

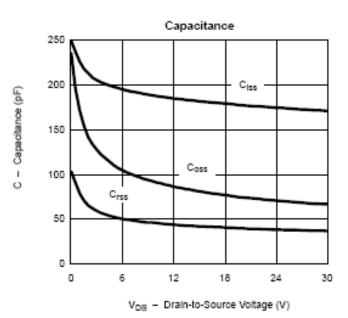
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	•						
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			***	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1.0		3.0	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
Zero Gate Voltage Drain Current		VDS=30V,VGS=1.0V			1	uA	
	IDSS	VDS=30V,VGS=0.0V TJ=55°C			10		
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 10V$	6			A	
	ID(0II)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	4				
Drain-Source On-Resistance	RDS(on)	$V_{GS} = 10V, I_{D} = 2.8A$		0.050	0.065	Ω	
F		VGS =4.5V,ID=2.3A		0.075	0.090	C	
Forward Transconductance	gfs	VDS=4.5V,ID=2.8A		4.6		S	
Diode Forward Voltage	Vsd	Is=1.25A,VGS=0V		0.82	1.2	V	
Dynamic							
Total Gate Charge	Qg	VDS=15VGS=10V ID=2.5		4.5	10	nC	
Gate-Source Charge	Qgs			0.8			
Gate-Drain Charge	Qgd			1.0			
Input Capacitance	Ciss			240		pF	
Output Capacitance	Coss	V _{DS} =15V _{GS} =0V f=1MHz		110			
Reverse Transfer Capacitance	Crss			17			
Turn-On Time	td(on)	VDD=15RL=15		8	20	nS	
	tr			12	30		
Turn-Off Time	td(off)	ID=1.0A,VGEN=10 $RG=6\Omega$		17	35		
	tf	110 022		8	20		

TYPICAL CHARACTERISTICS

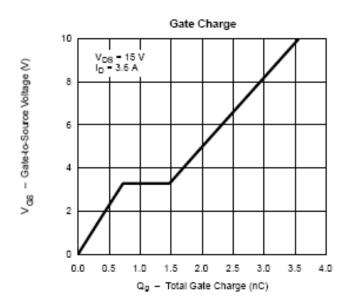


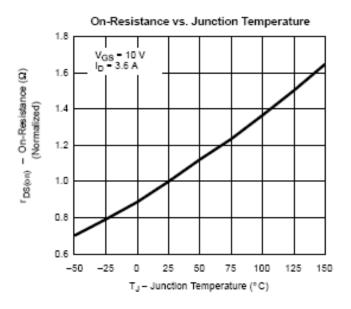


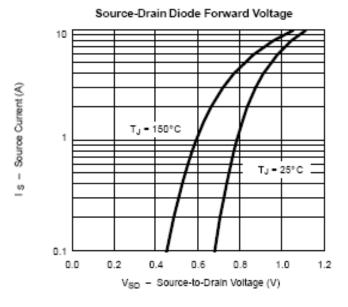


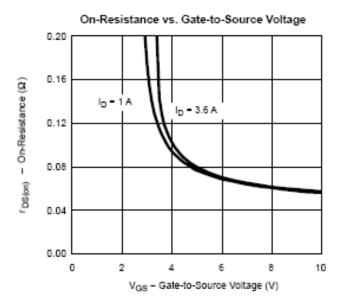


TYPICAL CHARACTERISTICS

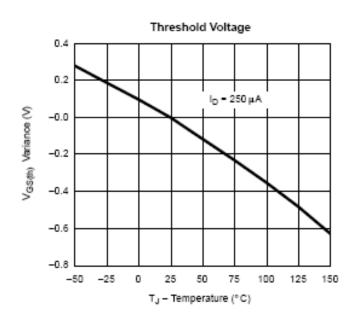


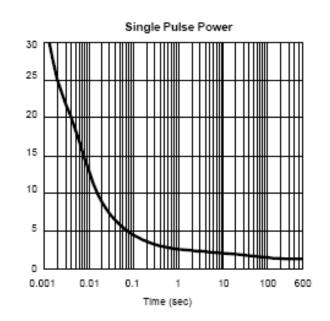






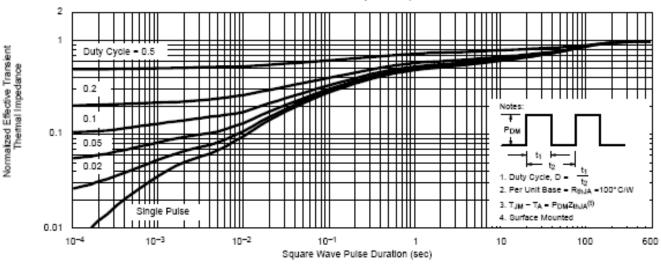
TYPICAL CHARACTERISTICS





Normalized Thermal Transient Impedance, Junction-to-Ambient

Power (W)



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